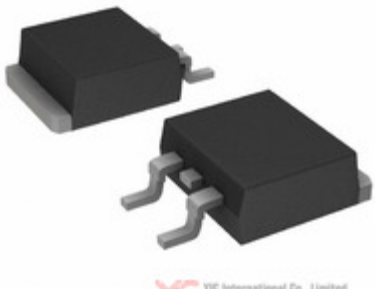

	<h2 style="color: red;">SUD50N04-8M8P-4GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SUD50N04-8M8P-4GE3
	Hersteller / Marke: Vishay / Siliconix
	Teil der Beschreibung: MOSFET N-CH 40V 14A TO-252
	Datenblätter:  SUD50N04-8M8P-4GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 32030 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SUD50N04-8M8P-4GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 40V 14A TO-252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	32030 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	3.1W (Ta), 48.1W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	14A (Ta), 50A (Tc)
Rds On (Max) @ Id, Vgs	8.8 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	56nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2400pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

SUD50N04-8M8P-4GE3 ist neu im Original, Suche SUD50N04-8M8P-4GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N04-8M8P-4GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SUD50N04-8M8P-4GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD50N04-37P-T4-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 5.4A TO252</p>	 <p>SUD50N06-07L-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 96A TO252</p>	 <p>SUD50N04-37P-E3-4GE3 VISHAY SUD50N04-37P-E3-4GE3 VISHAY</p>	 <p>SUD50N06 INF INF TO-252</p>
 <p>SUD50N04-8M8P-E3 V SUD50N04-8M8P-E3 V</p>	 <p>SUD50N06-07L VISHAY SUD50N06-07L VISHAY</p>	 <p>SUD50N04-8M8P-4GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 14A TO-252</p>	 <p>SUD50N04-37P-T4-E3 Vishay / Siliconix MOSFET N-CH 40V 5.4A TO252</p>

heiße Teile

Mehr

⊛ SUD50N03A	↔ SUD50N04-05L	⇒ SUD50N04-05L-E3	D SUD50N04-05L-E3	⇒ SUD50N04-06H
⊠ SUD50N04-06P	⊛ SUD50N04-07	D SUD50N04-07-T4-GE3	⇒ SUD50N04-07L	⇒ SUD50N04-07L-E3
⊛ SUD50N04-09H	⊠ SUD50N04-09H-E3	⊛ SUD50N04-09H-E3	↔ SUD50N04-09L-E3	⇒ SUD50N04-10P-E3
D SUD50N04-13P	⊛ SUD50N04-13P-E3	⊠ SUD50N04-16P	⊛ SUD50N04-25P	⇒ SUD50N04-37P
⇒ SUD50N04-37P-E3	↔ SUD50N04-37P-E3-4GE3	⊛ SUD50N04-37P-T4-GE3	⊠ SUD50N04-8M8P	⇒ SUD50N04-8M8P-4GE3
↔ SUD50N04-8M8P-E3	⇒ SUD50N06-07L	D SUD50N06-07L-GE3	⊛ SUD50N06-07L-GE3	⊠ SUD50N06-08H
⊛ SUD50N06-09L	D SUD50N06-09L-E3	⇒ SUD50N06-09L-E3	↔ SUD50N06-16	⇒ SUD50N06-36
⊠ SUD50N06L-09	⊛ SUD50N10-18P	↔ SUD50N10-18P-E3	⇒ SUD50N10-18P-E3	⇒ SUD50N10-18P-T4-E3
⊛ SUD50N10-34P	⊠ SUD50NP04-62-4-E3	⊛ SUD50NP04-62-T4-E3	D SUD50NP04-77P	⇒ SUD50P04-08
↔ SUD50P04-08-GE3	⊛ SUD50P04-08-GE3	⊠ SUD50P04-08L	⊛ SUD50P04-09L	⇒ SUD50P04-09L-E3

Contact us: Info@Y-IC.com

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